

Attorney Docket No. 061063-0311751
Client Reference: OSP-16220

PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of: TAKASHI SHIBAYAMA, YOSHIO MURAKAMI and TAKAYUKI SHINGYOJI

Application No.:
Filed: September 3, 2004

Confirmation No:
Group No.:
Examiner

For: PROCESS FOR PRODUCING SILICON SINGLE CRYSTAL LAYER AND SILICON SINGLE CRYSTAL LAYER

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

APPLICATION DATA SHEET
37 C.F.R. § 1.76

BIBLIOGRAPHIC DATA

1. Applicant information

First applicant: TAKASHI SHIBAYAMA
Citizenship: JAPAN
Residence: Kishima-gun, JAPAN

Second applicant: YOSHIO MURAKAMI
Citizenship: JAPAN
Residence: Saitama-shi, JAPAN

Third applicant: TAKAYUKI SHINGYOJI
Citizenship: JAPAN
Residence: Saitama-shi, JAPAN

2. Correspondence information

Correspondence for this application should be addressed as follows:

Customer No.: 00909

3. Application information

Title of Invention: PROCESS FOR PRODUCING SILICON SINGLE CRYSTAL LAYER AND SILICON SINGLE CRYSTAL LAYER

Docket number assigned to this application: 061063-0311751
Suggested Classification: Class:

Subclass:
Technology Center to which subject matter is assigned:

Total number of drawing sheets: 8
Type of application: Utility
Application is to be published. Suggested drawing figure for publication: 1

Secrecy order under § 5.2:

This application does not disclose subject matter of an application which is under a secrecy order pursuant to § 5.2.

4. Representative information

The following have a power of attorney or authorization of agent in this application:

Customer No.: 00909

5. Domestic Priority information

Domestic priority for this application is claimed as follows:

35 U.S.C. § 365(c):
Application No.: PCT/JP03/02568
Filed: March 5, 2003
Status: Pending
Relationship: Parent

6. Foreign priority information

Foreign priority is claimed for this application as follows:

Country: JAPAN
Application No.: 2002-059182
Filing Date: March 5, 2002
Status: Pending

Country: JAPAN
Application No.: 2002-261286
Filing Date: September 6, 2002
Status: Pending

7. Assignee information


The assignee(s) of this application is/are:

Sumitomo Mitsubishi Silicon Corporation
2-1, Shibaura 1-chome, Minato-ku
Tokyo,
JAPAN

Extent of interest of assignee in application: 100%

Date: September 3, 2004

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